

4 norm. ▽

U_{we} (V)	-8.9	-11.4	-7.9	-7.8	-7.7	-7.6	-7.5	-6.1	-4.1	-2	X	0.6	1.2	1.5	1.8	2.0	2.1	2.2	2.3	2.4	2.5
I_D (mA)	12.4	6.58	2.47	1.77	1.27	0.93	0.7	0.6	0.4	0.1	X	0.09	0.14	0.24	0.46	21.2	22.6	23.7	26.5	27.7	28.6
U_D (V)	-8.93	-8.28	-7.53	-7.52	-7.51	-7.5	-7.47	-6.74	-4.12	-2	X	0.668	1.2	1.46	1.87	1.01	1.04	1.05	1.08	1.1	1.103

I_D (mA)	15	12.5	11.6	9.4	7.7	6.3	5	3.3	2.3	1.7	X	0.25	2.6	2.9	3.2	3.5	3.9	4.3	4.9	5.2	5.4
U_D (V)	-15.4	-11.5	-6.5	3.3	1.8	-1	-0.6	-0.3	-0.2	-0.1	X	0.25	1.88	3.73	7.3	11.4	17.1	24	29.8	34	
I_D (mA)	13.5	11.55	9.4	7.7	6.3	4.97	3.28	2.35	1.72	X	2.44	2.6	2.9	3.1	3.2	3.39	3.53	3.87	3.8	3.79	

I_D (mA)	9.4	8.9	8.4	8.2	8.1	7.9	7.7	7.6	7.5	7.4	X	0.6	0.7	0.9	1.1	1.3	1.6	1.8	2.0	2.1	2.4
U_D (V)	-32.5	-24.2	-16.3	-13.3	-11	-8	-3.5	-1.5	-0.76	-0.01	X	0.65	3.5	7.2	9.9	16.5	20	23.6	25.3	31.5	
I_D (mA)	7.84	7.75	7.66	7.63	7.6	7.57	7.5	7.5	7.49	7.4	X	0.62	0.71	0.77	0.8	0.82	0.86	0.88	0.9	0.9	0.92

Charakterystyka Prądowo - Napięciowa Diody Półprzewodnikowej $I_D = f(U_D)$

